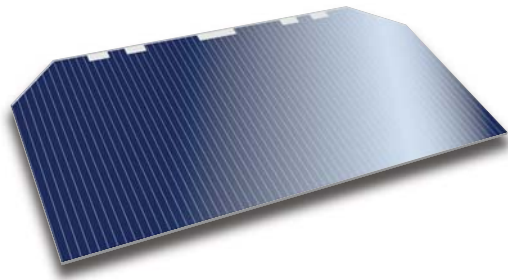


ATJM Photovoltaic Cell

Advanced Triple-Junction with Monolithic Diode Solar Cell for Space Applications



SPACE PHOTOVOLTAICS



27.0% Minimum Average Efficiency

Features & Characteristics

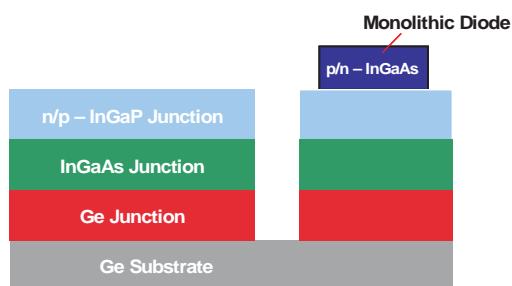
- Advanced Triple-Junction (ATJ) InGaP/InGaAs/Ge Solar Cells with n-on-p Polarity on 140- μm Uniform Thickness Substrate
- Fully space-qualified with proven flight heritage in LEO and GEO environments
- Fully Space-Qualified Monolithic Bypass Diode Protection
- Lowest solar cell mass of 84 mg/cm²
- Excellent radiation resistance with P/Po = 0.89 @ 1-MeV, 5E14 e/cm² fluence
- Excellent Mechanical Strength for Reduced Attrition during Assembly and Laydown
- Weldable or Solderable contacts
- Available at EPI, cell, CIC or panel configuration
- Standard and Custom Sizes Available

Typical Performance Data

Solar Cell Electrical Output Parameters	
Electrical Parameters @ AM0 (135.3 mW/cm ²)	27%
V _{oc}	2.575V
J _{sc}	16.9 mA/cm ²
V _{mp}	2.285V
J _{mp}	16.0 mA/cm ²

Monolithic Diode Electrical Performance	
V _{RB} < 2.0 V @ I _{RB}	500 mA, 28°
I _{RB} < 50 μA @ V _{RB}	2.5V (Dark), 28°C
I _{RB} < 200 μA @ V _{RB}	2.5V (Illuminated), 28°C
I _{RB} < 10 μA @ V _{RB}	2.5V (Dark), -150°C
I _{RB} < 1 μA @ V _{RB}	2.5V (Dark), +120°C

ATJM Cell Structure



Schematic Cross-Sectional View

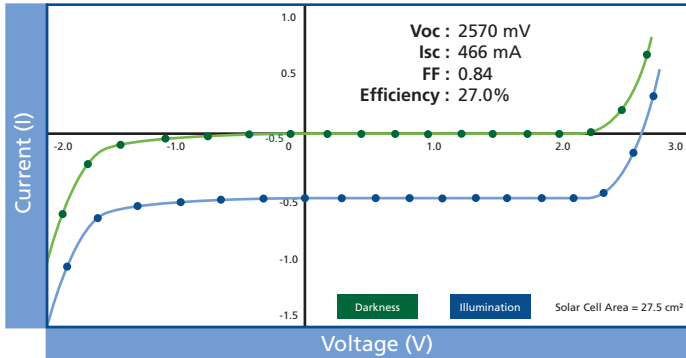
ATJM Photovoltaic Cell

Advanced Triple-Junction with Monolithic Diode Solar Cell for Space Applications



SPACE PHOTOVOLTAICS

Typical Current (I) / Voltage(V) Plot



Key Space Qualification Results

Test Performed	Industry Quality Standard	Typical Test Results
Metal Contact Thickness	4-10 μm	6 μm
Dark Current degradation after reverse bias	Δ I _{spec} <2%	<0.4%
Electrical performance after 2,000 thermal cycles -180°C to +95°C	<2%	<0.7%
High-Temperature Anneal at 200°C for >5,000 hrs.	<2%	No measurable difference
Contact pull strength	>300 grams	>600 grams
Electrical performance degradation after 40 day humidity exposure at 60°C and 95% relative humidity	<1.5%	No measurable difference

■ For complete qualification results, please request EMCORE's ATJ Qual Report EWRP036

About EMCORE Corporation



Emcore Photovoltaics Albuquerque, NM

- Incorporated in 1984
- Appx. 900 Employees
- Nasdaq: EMKR

Radiation Performance at 1 MeV Electron Irradiation, EOL/BOL Ratios

Fluence (e/cm ²)	Voc	Isc	Vmp	Imp	Pmp	Efficiency
5E 13	0.97	1.00	0.97	1.00	0.97	0.97
1E 14	0.96	1.00	0.96	1.00	0.96	0.96
5E 14	0.92	0.98	0.92	0.96	0.89	0.89
1E 15	0.90	0.96	0.90	0.94	0.85	0.85
3E 15	0.86	0.90	0.85	0.87	0.74	0.74

Temperature Coefficients

Fluence (e/cm ²)	ΔVoc/ΔT (mV/°C)	Jsc/ΔT ⁽¹⁾ (μA/°C)	Vm/ΔT (mV/°C)	Jmp/ΔT ⁽²⁾ (μA/°Ccm)
BOL	-5.48	+12	-5.93	+11
5E 13	-5.49	+10	-5.68	+7
1E 14	-5.46	+11	-5.66	+7
5E 14	-5.61	+12	-5.92	+12
1E 15	-5.77	+12	-6.14	+13

- ⁽¹⁾ Jsc is the symbol for normalized Isc
- ⁽²⁾ Jmp is the symbol for normalized Imp

Regulatory



EMCORE CORPORATION
ISO 9001 CERTIFIED



EMCORE PHOTOVOLTAICS
AS9100 CERTIFIED